

# 4V Drive Pch+Pch MOSFET

### SH8J65

### Structure

Silicon P-channel MOSFET

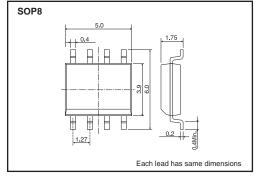
### Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (SOP8).

### Application

Switching

### •Dimensions (Unit : mm)



### Packaging specifications

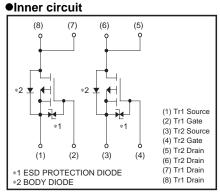
	Package	Taping
Туре	Code	ТВ
	Basic ordering unit (pieces)	2500
SH8J65		0

### ●Absolute maximum ratings (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2.>

-					
Parameter		Symbo	bl	Limits	Unit
Drain-source voltage		Vdss		-30	V
Gate-source voltage		Vgss		±20	V
Decis compact	Continuous	ID		±7.0	A
Drain current	Pulsed	I <sub>DP</sub>	*1	±28	A
Source current	Continuous	ls		-1.6	А
(Body diode)	Pulsed	I <sub>SP</sub>	*1	-28	А
Total power dissipation		Pp	*2	2.0	W / TOTAL
Total power dissipation		ID		1.4	W / ELEMENT
Channel temperature		Tch		150	٥C
Range of Storage temperature		Tstg		-55 to +150	°C
				•	

\*1 Pw≤10µs, Duty cycle≤1% \*2 Mounted on a ceramic board



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# •Electrical characteristics (Ta=25°C)

<pre><it characterist<="" is="" pre="" same="" the=""></it></pre>		ne Ir1	and Ir	2.>		
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μΑ	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V(BR) DSS	-30	_	_	V	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	IDSS		-	-1	μA	VDS=-30V, VGS=0V
Gate threshold voltage	VGS (th)	-1.0	_	-2.5	V	$V_{DS} = -10V, I_{D} = -1mA$
Ctatia drain aguras an atata		-	21.5	29.0	mΩ	$I_D = -7A, V_{GS} = -10V$
Static drain-source on-state resistance	RDS (on)	-	29.0	39.0	mΩ	$I_D = -3.5 A$ , $V_{GS} = -4.5 V$ *
resistance		-	31.0	40.8	mΩ	ID= -3.5A, VGS= -4.0V *
Forward transfer admittance	Y <sub>fs</sub> *	6.0	_	_	S	V <sub>DS</sub> =-10V, I <sub>D</sub> =-7A *
Input capacitance	Ciss	-	1200	_	pF	V <sub>DS</sub> =-10V
Output capacitance	Coss	-	170	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	-	170	-	pF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub> *	-	12	_	ns	Vdd≒-15V
Rise time	tr *	-	40	-	ns	D = -3.5A
Turn-off delay time	td (off) *	-	80	_	ns	VGs= −10V R∟=4.3Ω
Fall time	tr *	-	65	-	ns	R <sub>G</sub> =10Ω
Total gate charge	Qg *	_	18	-	nC	Vdd≒-15V
Gate-source charge	Q <sub>gs</sub> *	-	3.5	-	nC	$I_{D} = -7A$ $V_{GS} = -5V$
Gate-drain charge	Q <sub>gd</sub> *	_	6.5	_	nC	$R_{L}=2.1\Omega / R_{G}=10\Omega$
*Pulsed						

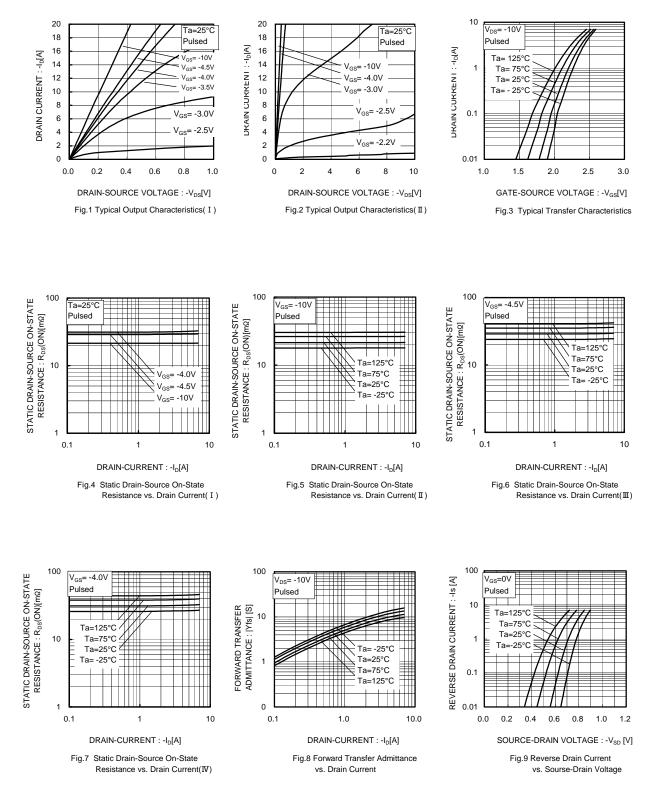
\*Pulsed

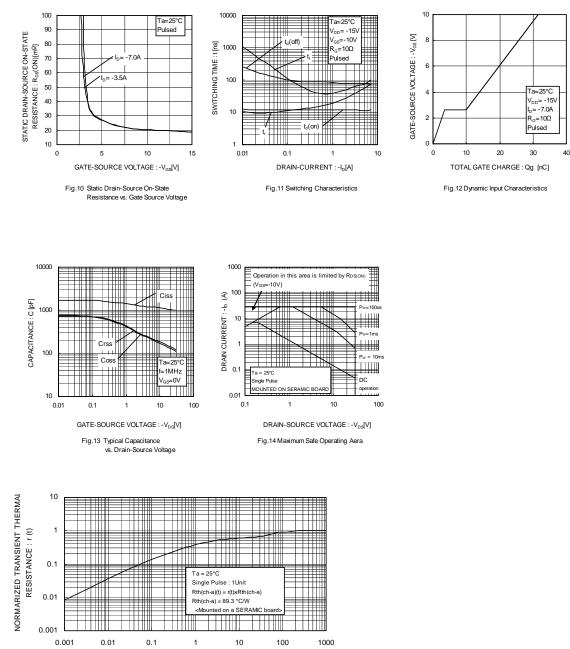
### ●Body diode characteristics (Source-Drain) (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsd *	_	_	-1.2	V	Is= -7A, Vgs=0V
*Pulsed						

### •Electrical characteristic curves





PULSE WIDTH : Pw(s)

Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

### Measurement circuits

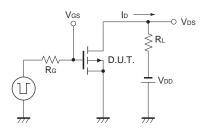


Fig.16 Switching Time Test Circuit

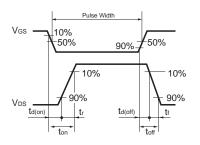


Fig.17 Switching Time Waveforms

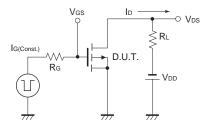


Fig.18 Gate Charge Test Circuit

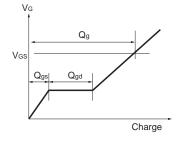


Fig.19 Gate Charge Waveform

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